TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM5N15FU

1. Applications

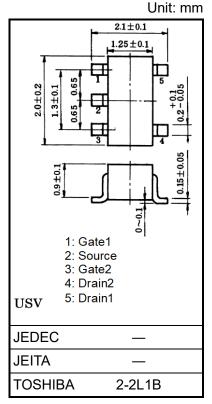
- · High Speed Switching Applications
- Analog Switch Applications

2. Features

- Small package
- Low ON resistance: R_{DS} (ON) = 4.0 Ω (max) (@VGS = 4 V)
- : R_{DS} (ON) = 7.0 Ω (max) (@VGS = 2.5 V)

3. Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common) (Note)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	30	V	
Gate-Source voltage		V_{GSS}	±20	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25°C)		P _D (Note1)	200	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

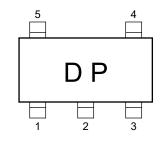


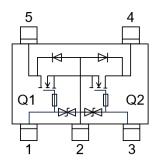
Weight: 6 mg (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note1: Total rating

4. Marking, Equivalent Circuit (top view)





5. Handling Precaution

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Start of commercial production 2001-02

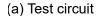


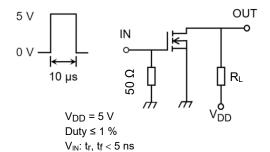
6. Electrical Characteristics

6.1. Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic		Symbol	Test Condition	Min	Тур	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±1	μΑ
Drain-Source breakdown voltage		V _{(BR) DSS}	I _D = 0.1 mA, V _{GS} = 0 V	30	-	-	V
Drain cut-off current		I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	-	-	1	μΑ
Gate threshold voltage		V_{th}	V _{DS} = 3 V, I _D = 0.1 mA	0.8	-	1.5	V
Forward transfer admittance		Y _{fs}	V _{DS} = 3 V, I _D = 10 mA	25	-	-	mS
Drain-Source ON resistance		R _{DS (ON)}	I _D = 10 mA, V _{GS} = 4 V	-	2.2	4.0	Ω
			I _D = 10 mA, V _{GS} = 2.5 V	-	4.0	7.0	
Input capacitance		C _{iss}	V _{DS} = 3 V, V _{GS} = 0 V, f = 1 MHz	-	7.8	-	pF
Reverse transfer capacitance		C _{rss}		-	3.6	-	pF
Output capacitance		Coss		-	8.8	-	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA},$ $V_{GS} = 0 \text{ to } 5 \text{ V}$ See 6.2	-	50	-	ns
	Turn-off time	t _{off}		-	180	-	

6.2. Switching Time Test Circuit (Q1, Q2 common)

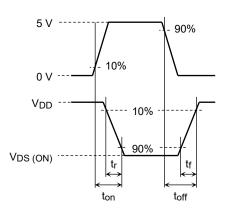




 $(Z_{out} = 50 \Omega)$ Common Source Ta = 25°C

(b) VIN

(c) VOUT



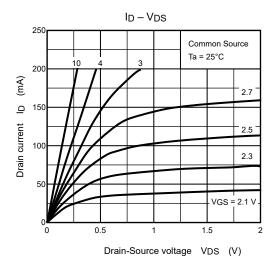
6.3. Precaution

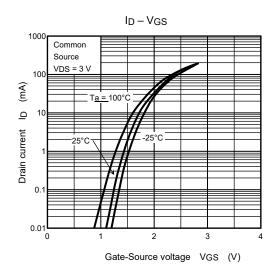
V_{th} can be expressed as voltage between gate and source when low operating current value is I_D = 100 μAfor this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th}. (Relationship can be established as follows: V_{GS (off)} < V_{th} < V_{GS (on)})

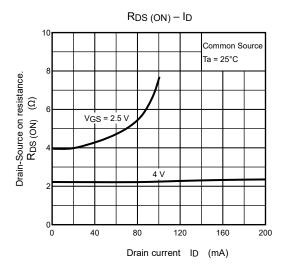
Please take this into consideration for using the device.

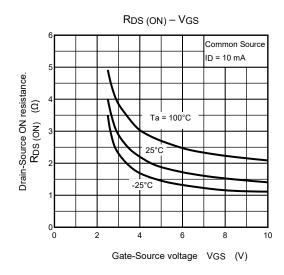


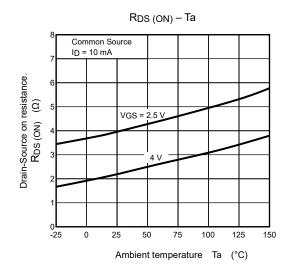
7. Characteristic Chart(Q1, Q2 common) (Note)

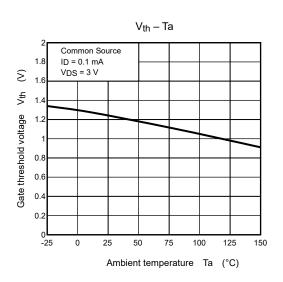






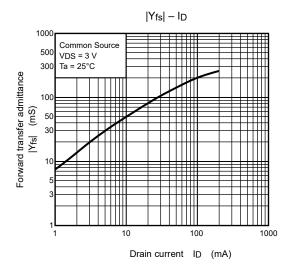


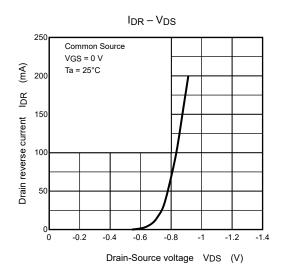


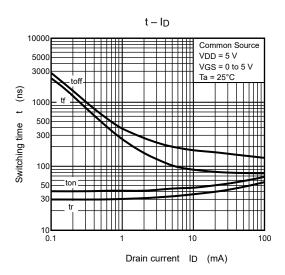


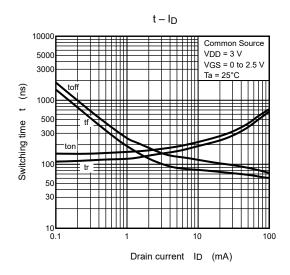
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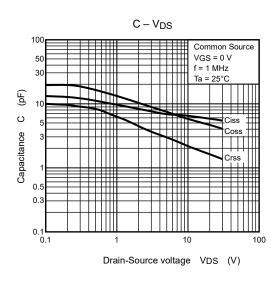


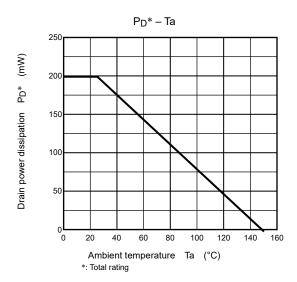












Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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